

Reference Specification

150°C Operation Leaded MLCC for Automotive (Powertrain/Safety) RHE Series

Product specifications in this catalog are as of Apr. 2024, and are subject to change or obsolescence without notice.

Please consult the approval sheet before ordering. Please read rating and Cautions first.

⚠ CAUTION

1. OPERATING VOLTAGE

Do not apply a voltage to the capacitor that exceeds the rated voltage as called out in the specifications.

- 1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.
- (1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage. When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.
- (2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.

Typical Voltage Applied to the DC Capacitor

DC Voltage	DC+AC Voltage A	AC Voltage	Pulse Voltage				
E	E	E	E				

(E: Maximum possible applied voltage.)

1-2. Influence of over voltage

Over voltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers. The time duration until breakdown depends on the applied voltage and the ambient temperature.

Use a safety standard certified capacitor in a power supply input circuit (AC filter), as it is also necessary to consider the withstand voltage and impulse withstand voltage defined for each device.

2. OPERATING TEMPERATURE AND SELF-GENERATED HEAT

Keep the surface temperature of a capacitor below the upper limit of its rated operating temperature range. Be sure to take into account the heat generated by the capacitor itself.

When the capacitor is used in a high-frequency current, pulse current or the like, it may have the self-generated heat due to dielectric-loss. In case of Class 2 capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied voltage should be the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied to the load such as self-generated heat is within 20 °C on the capacitors (Temp.Char. : X7R,X7S,X8L, etc.), applied to the load such as self-generated h

Since the self-heating is low in the Class 1 capacitors (Temp.Char.: C0G,U2J,X8G, etc.), the allowable power becomes extremely high compared to the Class 2 capacitors.

However, when a load with self-heating of 20°C is applied at the rated voltage, the allowable power may be exceeded. Please confirm that there is no rising trend of the capacitor's surface temperature and that the surface temperature of the capacitor does not exceed the maximum operating temperature.

Excessive generation of heat may cause deterioration of the characteristics and reliability of the capacitor.

When measuring the self-heating temperature, be aware that accurate measurement may not be possible due to the following effects.

- The heat generated by other parts
- Air flow such as convection and cooling fans
- Temperature sensor used for measuring surface temperature of capacitor
 In the case using a thermocouple, it is recommended that use a K thermocouple of Φ0.1mm with less heat capacity.

3. FAIL-SAFE

Capacitors that are cracked by dropping or bending of the board may cause deterioration of the insulation resistance, and result in a short.

If the circuit being used may cause an electrical shock, smoke or fire when a capacitor is shorted, be sure to install fail-safe functions, such as a fuse, to prevent secondary accidents.

4. OPERATING AND STORAGE ENVIRONMENT

The insulating coating of capacitors does not form a perfect seal; therefore, do not use or store capacitors in a corrosive atmosphere, especially where chloride gas, sulfide gas, acid, alkali, salt or the like are present. And avoid exposure to moisture. Before cleaning, bonding, or molding this product, verify that these processes do not affect product quality by testing the performance of a cleaned, bonded or molded product in the intended equipment. Store the capacitors where the temperature and relative humidity do not exceed 5 to 40 °C and 20 to 70%. Use capacitors within 6 months.

Use capacitors within 6 months after delivered. Check the solderability after 6 months or more. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high humidity conditions.

5. VIBRATION AND IMPACT

Do not expose a capacitor or its leads to excessive shock or vibration during use.

- 5-1. Mechanical shock due to being dropped may cause damage or a crack in the dielectric material of the capacitor.
 - Do not use a dropped capacitor because the quality and reliability may be deteriorated.
- 5-2. Excessive shock or vibration may cause to fatigue destruction of lead wires mounted on the circuit board. If necessary, take measures to hold a capacitor on the circuit boards by adhesive, molding resin or coating and other.
 - Please confirm there is no influence of holding measures on the product with an intended equipment.

6. SOLDERING

When soldering this product to a PCB/PWB, do not exceed the solder heat resistance specification of the capacitor. Subjecting this product to excessive heating could melt the internal junction solder and may result in thermal shocks that can crack the ceramic element.

Please verify that the soldering process does not affect the quality of capacitors.

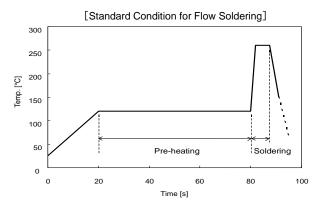
6-1. Flow Soldering

Soldering temperature : 260 °C max.

Soldering time : 7.5 s max.

Preheating temperature : 120 °C max.

Preheating time : 60 s max.



6-2. Reflow Soldering

Do not apply reflow soldering.

6-3. Soldering Iron

Temperature of iron-tip : 350 °C max.
Soldering iron wattage : 60 W max.
Soldering time : 3.5 s max.

7. BONDING AND RESIN MOLDING, RESIN COAT

In case of bonding, molding or coating this product, verify that these processes do not affect the quality of capacitor by testing the performance of a bonded or molded product in the intended equipment. In case of the amount of applications, dryness / hardening conditions of adhesives and molding resins containing organic solvents (ethyl acetate, methyl ethyl ketone, toluene, etc.) are unsuitable, the outer coating resin of a capacitor is damaged by the organic solvents and it may result, worst case, in a short circuit.

The variation in thickness of adhesive or molding resin may cause a outer coating resin cracking and/or ceramic element cracking of a capacitor in a temperature cycling.

8. TREATMENT AFTER BONDING AND RESIN MOLDING, RESIN COAT

When the outer coating is hot (over 100 °C) after soldering, it becomes soft and fragile.

So please be careful not to give it mechanical stress.

Failure to follow the above cautions may result, worst case, in a short circuit and cause fuming or partial dispersion when the product is used.

9. LIMITATION OF APPLICATIONS

The products listed in the specification(hereinafter the product(s) is called as the "Product(s)") are designed and manufactured for applications specified in the specification. (hereinafter called as the "Specific Application")

We shall not warrant anything in connection with the Products including fitness, performance, adequateness, safety, or quality, in the case of applications listed in from (1) to (11) written at the end of this precautions, which may generally require high performance, function, quality, management of production or safety.

Therefore, the Product shall be applied in compliance with the specific application.

WE DISCLAIM ANY LOSS AND DAMAGES ARISING FROM OR IN CONNECTION WITH THE PRODUCTS INCLUDING BUT NOT LIMITED TO THE CASE SUCH LOSS AND DAMAGES CAUSED BY THE UNEXPECTED ACCIDENT, IN EVENT THAT (i) THE PRODUCT IS APPLIED FOR THE PURPOSE WHICH IS NOT SPECIFIED AS THE SPECIFIC APPLICATION FOR THE PRODUCT, AND/OR (ii) THE PRODUCT IS APPLIED FOR ANY FOLLOWING APPLICATION PURPOSES FROM (1) TO (11) (EXCEPT THAT SUCH APPLICATION PURPOSE IS UNAMBIGUOUSLY SPECIFIED AS SPECIFIC APPLICATION FOR THE PRODUCT IN OUR CATALOG SPECIFICATION FORMS, DATASHEETS, OR OTHER DOCUMENTS OFFICIALLY ISSUED BY US*)

- 1. Aircraft equipment
- 2. Aerospace equipment
- 3. Undersea equipment
- 4. Power plant control equipment
- 5. Medical equipment
- 6. Transportation equipment
- 7. Traffic control equipment
- 8. Disaster prevention/security equipment
- 9. Industrial data-processing equipment
- 10. Combustion/explosion control equipment
- 11. Equipment with complexity and/or required reliability equivalent to the applications listed in the above.

For exploring information of the Products which will be compatible with the particular purpose other than those specified in the specification, please contact our sales offices, distribution agents, or trading companies with which you make a deal, or via our web contact form.

Contact form: https://www.murata.com/contactform

*We may design and manufacture particular Products for applications listed in (1) to (11). Provided that, in such case we shall unambiguously specify such Specific Application in the specification without any exception

Therefore, any other documents and/or performances, whether exist or non-exist, shall not be deemed as the evidence to imply that we accept the applications listed in (1) to (11).

NOTICE

1. CLEANING

- 1-1. Please evaluate the capacitor using actual cleaning equipment and conditions to confirm the quality, and select the solvent for cleaning.
- 1-2. Unsuitable cleaning may leave residual flux or other foreign substances, causing deterioration of electrical characteristics and the reliability of the capacitors.
- 1-3. To perform ultrasonic cleaning, observe the following conditions.

Rinse bath capacity: Output of 20 watts per liter or less.

Rinsing time: 5 min maximum.

Do not vibrate the PCB/PWB directly.

Excessive ultrasonic cleaning may lead to fatigue destruction of the lead wires.

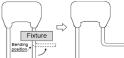
2. SOLDERING AND MOUNTING

2-1. Insert the lead wire into the PCB with a distance appropriate to the lead space.

If the lead wires are inserted into different spacing holes, cracks may occur in the outer resin or the internal element.

2-2. When bending the lead wire, excessive force applied to the capacitor body may cause cracks in the outer resin or the internal element. Hold the lead wire closer to the capacitor body than the lead wire bending position with the fixture, then bend it.

(See the right figure)



- 2-3. When cutting and clinching the lead wire, do not apply excessive force to the capacitor body.
- 2-4. When soldering, insert the lead wire into the PCB without mechanically stressing the lead wire.

3. CAPACITANCE CHANGE OF CAPACITORS

Class 2 capacitors (Temp.Char. : X7R,X7S,X8L etc.)

Class 2 capacitors an aging characteristic, whereby the capacitor continually decreases its capacitance slightly if the capacitor leaves for a long time. Moreover, capacitance might change greatly depending on a surrounding temperature or an applied voltage. So, it is not likely to be able to use for the time constant circuit.

Please contact us if you need a detail information.

4. CHARACTERISTICS EVALUATION IN THE ACTUAL SYSTEM

- 4-1. Evaluate the capacitor in the actual system, to confirm that there is no problem with the performance and specification values in a finished product before using.
- 4-2. Since a voltage dependency and temperature dependency exists in the capacitance of Class 2 ceramic capacitors, the capacitance may change depending on the operating conditions in the actual system. Therefore, be sure to evaluate the various characteristics, such as the leakage current and noise absorptivity, which will affect the capacitance value of the capacitor.
- 4-3. In addition, voltages exceeding the predetermined surge may be applied to the capacitor by the inductance in the actual system.

Evaluate the surge resistance in the actual system as required.

4-4. When using Class 2 ceramic capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated. Moreover, when the mechanical vibration or shock is added to capacitor, noise may occur.

\triangle NOTE

- 1. Please make sure that your product has been evaluated in view of your specifications with our product being mounted to your product.
- 2. You are requested not to use our product deviating from this product specification.

1. Application

This product specification is applied to Leaded MLCC RHE series.

- 1. Specific applications:
- · Automotive powertrain/safety equipment: Products that can be used for automotive equipment related to running, turning, stopping, safety devices, etc., or equipment whose structure, equipment, and performance are legally required to meet technical standards for safety assurance or environmental protection.
- · Automotive infotainment/comfort equipment: Products that can be used for automotive equipment such as car navigation systems and car audio systems that do not directly relate to human life and whose structure, equipment, and performance are not specifically required by law to meet technical standards for safety assurance or environmental protection.
- ·Medial Equipment [GHTF A/B/C] except for Implant Equipment: Products suitable for use in medical devices designated under the GHTF international classifications as Class A or Class B (the functions of which are not directly involved in protection of human life or property) or in medical devices other than implants designated under the GHTF international classifications as Class C (the malfunctioning of which is considered to pose a comparatively high risk to the human body).
- 2. Unsuitable Application: Applications listed in "Limitation of applications" in this product specification.

2. Rating

Applied maximum temperature up to 150°C

Note: Maximum accumulative time to 150°C is within 2000 hours.

• Part Number Configuration

ex.) RHE H03 1E 226 M1 Series Temperature Rated Capacitance Capacitance Dimension Lead Individual Package Characteristics Tolerance (LxW) Specification Voltage Style

Series

Code	Content
RHE	Epoxy coated, 150°C max.

Temperature Characteristics

Code	Temp. Char.	Temp. Range	Cap. Change	Standard Temp.	Operating Temp. Range
1.0	X8L	-55 ∼ 125°C	+/-15%	25°C	-55 ∼ 150°C
L8	(Murata code)	125~150°C	+15/-40%	25 C	-55° 150 C

Rated Voltage

<u> </u>	
Code	Rated voltage
1E	DC25V
1H	DC50V
2A	DC100V

Capacitance

The first two digits denote significant figures; the last digit denotes the multiplier of 10 in pF. ex.) In case of 226.

$$22 \times 10^6 = 22000000 \text{ pF}$$

• Capacitance Tolerance

Code	Capacitance Tolerance
K	+/-10%
М	+/-20%

• Dimension (LxW)

Please refer to [Part number list].

• Lead Style

*Lead wire is "solder coated CP wire".

Code	Lead Style	Lead spacing (mm)
A2	Straight type	2.5+/-0.8
DB	Straight taping type	2.5+0.4/-0.2
K1	Inside crimp type	5.0+/-0.8
M1	Inside crimp taping type	5.0+0.6/-0.2

• Individual Specification

Murata's control code.

Please refer to [Part number list].

Package

╌.	-	
	Code	Package
	Α	Taping type of Ammo
	В	Bulk type

3. Marking

Temp. char. : Letter code : 8 (X8L char.)

Capacitance : 3 digit numbers

Capacitance tolerance : Code

Rated voltage : Letter code : 2 (DC25V. Except dimension code : 0,1)

Letter code: 5 (DC50V. Except dimension code: 0,1)
Letter code: 1 (DC100V. Except dimension code: 0,1)

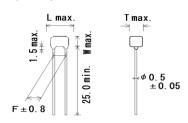
Company name code : Abbreviation : (Except dimension code : 0,1)

(Ex.)

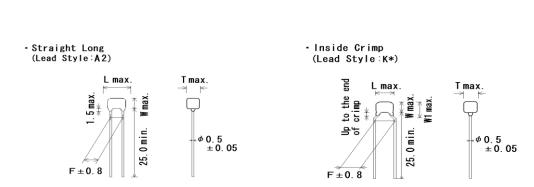
(EX.)			
Rated voltage Dimension code	DC25V	DC50V	DC100V
0,1	8 105K	8 102K	8 103K
2	€ 475 K28	€ 6 225 K58	€ 224 K18
3,W	C 4226 K28	@ 106 K58	-

4. Part number list

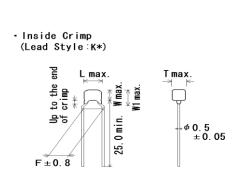
 Straight Long (Lead Style: A2)



Customer	Murata Part Number	T.C.	DC Rated	Cap.	Сар.		Dime	ension ((mm)		Dimension (LxW)	Pa
Part Number	Ividiata i art Number	1.0.	Volt. (V)	Оар.	Tol.	L	W	W1	F	Т	Lead Style	(pc
	RHEL81E104K0A2H03B	X8L	25	0.1µF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL81E154K0A2H03B	X8L	25	0.15µF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL81E224K0A2H03B	X8L	25	0.22µF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL81E334K1A2H03B	X8L	25	0.33µF	±10%	4.0	3.5	-	2.5	2.5	1A2	50
	RHEL81E474K1A2H03B	X8L	25	0.47µF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL81E684K1A2H03B	X8L	25	0.68µF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL81E105K1A2H03B	X8L	25	1.0µF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL81E155K2A2H03B	X8L	25	1.5µF	±10%	5.5	4.0	-	2.5	3.15	2A2	5
	RHEL81E225K2A2H03B	X8L	25	2.2µF	±10%	5.5	4.0	-	2.5	3.15	2A2	5
	RHEL81E335K2A2H03B	X8L	25	3.3µF	±10%	5.5	4.0	-	2.5	3.15	2A2	5
	RHEL81E475K2A2H03B	X8L	25	4.7µF	±10%	5.5	4.0	-	2.5	3.15	2A2	5
	RHEL81E106K3A2H03B	X8L	25	10µF	±10%	5.5	5.0	-	2.5	4.0	3A2	5
	RHEL81H221K0A2H03B	X8L	50	220pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL81H331K0A2H03B	X8L	50	330pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL81H471K0A2H03B	X8L	50	470pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H681K0A2H03B	X8L	50	680pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H102K0A2H03B	X8L	50	1000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H152K0A2H03B	X8L	50	1500pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H222K0A2H03B	X8L	50	2200pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H332K0A2H03B	X8L	50	3300pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H472K0A2H03B	X8L	50	4700pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H682K0A2H03B	X8L	50	6800pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H103K0A2H03B	X8L	50	10000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL81H153K0A2H03B	X8L	50	15000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL81H223K0A2H03B	X8L	50	22000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	
	RHEL81H333K0A2H03B	X8L	50	33000pF	±10%	3.6	3.5	_	2.5	2.5	0A2	5
	RHEL81H473K0A2H03B	X8L	50	47000pF	±10%	3.6	3.5	_	2.5	2.5	0A2	
	RHEL81H683K0A2H03B	X8L	50	68000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL81H104K0A2H03B	X8L	50	0.1µF	±10%	3.6	3.5	_	2.5	2.5	0A2	5
	RHEL81H154K1A2H03B	X8L	50	0.15µF	±10%	4.0	3.5	-	2.5	2.5	1A2	
	RHEL81H224K1A2H03B	X8L	50	0.22µF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL81H334K1A2H03B	X8L	50	0.33µF	±10%	4.0	3.5	_	2.5	2.5	1A2	5
	RHEL81H474K2A2H03B	X8L	50	0.47µF	±10%	5.5	4.0	_	2.5	3.15		,
	RHEL81H684K2A2H03B	X8L	50	0.47μΓ 0.68μF	±10%	5.5	4.0	-	2.5	3.15		5
	RHEL81H105K2A2H03B	X8L	50	1.0µF	±10%	5.5	4.0	-	2.5	3.15		5
	RHEL81H155K2A2H03B	X8L	50	1.5µF	±10%	5.5	4.0	_	2.5	3.15		5
	RHEL81H225K2A2H03B	X8L	50	2.2µF	±10%	5.5	4.0		2.5	3.15		5
	RHEL81H335K3A2H03B	X8L	50	3.3µF	±10%	5.5	5.0		2.5	4.0		5
	RHEL81H475K3A2H03B	X8L	50	3.3μF 4.7μF	±10%	5.5	5.0		2.5	4.0		5
	RHEL82A221K0A2H03B	X8L	100	4.7μF 220pF	±10%	3.6	3.5		2.5	2.5		5

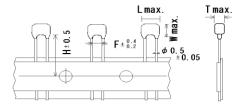


Customer	Murata Part Number	T.C.	DC Rated	Cap.	Сар.		Dime	ension (mm)		Dimension (LxW)	Pa
Part Number	Warda Far Namber	1.0.	Volt. (V)	оцр.	Tol.	L	W	W1	F	Т	Lead Style	
	RHEL82A331K0A2H03B	X8L	100	330pF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL82A471K0A2H03B	X8L	100	470pF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL82A681K0A2H03B	X8L	100	680pF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL82A102K0A2H03B	X8L	100	1000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	50
	RHEL82A152K0A2H03B	X8L	100	1500pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A222K0A2H03B	X8L	100	2200pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A332K0A2H03B	X8L	100	3300pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A472K0A2H03B	X8L	100	4700pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A682K0A2H03B	X8L	100	6800pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A103K0A2H03B	X8L	100	10000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A153K0A2H03B	X8L	100	15000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A223K0A2H03B	X8L	100	22000pF	±10%	3.6	3.5	-	2.5	2.5	0A2	5
	RHEL82A333K1A2H03B	X8L	100	33000pF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL82A473K1A2H03B	X8L	100	47000pF	±10%	4.0	3.5	-	2.5	2.5	1A2	5
	RHEL82A683K1A2H03B	X8L	100	68000pF	±10%	4.0	3.5	-	2.5	2.5	1A2	
	RHEL82A104K1A2H03B	X8L	100	0.1µF	±10%	4.0	3.5	-	2.5	2.5	1A2	
	RHEL82A154K2A2H03B	X8L	100	0.15µF	±10%	5.5	4.0	-	2.5	3.15	2A2	
	RHEL82A224K2A2H03B	X8L	100	0.22µF	±10%	5.5	4.0	-	2.5	3.15	2A2	
	RHEL81E104K0K1H03B	X8L	25	0.1µF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	
	RHEL81E154K0K1H03B	X8L	25	0.15µF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	
	RHEL81E224K0K1H03B	X8L	25	0.22µF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	
	RHEL81E334K1K1H03B	X8L	25	0.33µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	
	RHEL81E474K1K1H03B	X8L	25	0.47µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	5
	RHEL81E684K1K1H03B	X8L	25	0.68µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	5
	RHEL81E105K1K1H03B	X8L	25	1.0µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	5
	RHEL81E155K2K1H03B	X8L	25	1.5µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	5
	RHEL81E225K2K1H03B	X8L	25	2.2µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	5
	RHEL81E335K2K1H03B	X8L	25	3.3µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	5
	RHEL81E475K2K1H03B	X8L	25	4.7µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	5
	RHEL81E106K3K1H03B	X8L	25	10µF	±10%	5.5	5.0	7.5	5.0	4.0	3K1	5
	RHEL81E226MWK1H03B	X8L	25	22µF	±20%	5.5	7.5	10.0	5.0	4.0	WK1	5
	RHEL81H221K0K1H03B	X8L	50	220pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H331K0K1H03B	X8L	50	330pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H471K0K1H03B	X8L	50	470pF	±10%	3.6	3.5	6.0		2.5		5
	RHEL81H681K0K1H03B	X8L	50	680pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H102K0K1H03B	X8L	50	1000pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H152K0K1H03B	X8L	50	1500pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H222K0K1H03B	X8L	50	2200pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H332K0K1H03B	X8L	50	3300pF	±10%	3.6	3.5	6.0	5.0	2.5		5
	RHEL81H472K0K1H03B	X8L	50	4700pF	±10%	3.6	3.5	6.0	5.0	2.5		5



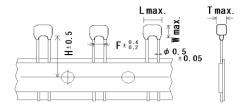
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Customer	Murata Part Number	T.C.	DC Rated	Cap.	Сар.		Dime	ension (mm)		Dimension (LxW)	Pack qty.
Part Number	Marata Fare Names	1.0.	Volt. (V)	oup.	Tol.	L	W	W1	F	Т	Lead Style	
	RHEL81H682K0K1H03B	X8L	50	6800pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H103K0K1H03B	X8L	50	10000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H153K0K1H03B	X8L	50	15000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H223K0K1H03B	X8L	50	22000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H333K0K1H03B	X8L	50	33000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H473K0K1H03B	X8L	50	47000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H683K0K1H03B	X8L	50	68000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H104K0K1H03B	X8L	50	0.1µF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL81H154K1K1H03B	X8L	50	0.15µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL81H224K1K1H03B	X8L	50	0.22µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL81H334K1K1H03B	X8L	50	0.33µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL81H474K2K1H03B	X8L	50	0.47µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL81H684K2K1H03B	X8L	50	0.68µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL81H105K2K1H03B	X8L	50	1.0µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL81H155K2K1H03B	X8L	50	1.5µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL81H225K2K1H03B	X8L	50	2.2µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL81H335K3K1H03B	X8L	50	3.3µF	±10%	5.5	5.0	7.5	5.0	4.0	3K1	500
	RHEL81H475K3K1H03B	X8L	50	4.7µF	±10%	5.5	5.0	7.5	5.0	4.0	3K1	500
	RHEL81H106MWK1H03B	X8L	50	10µF	±20%	5.5	7.5	10.0	5.0	4.0	WK1	500
	RHEL82A221K0K1H03B	X8L	100	220pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A331K0K1H03B	X8L	100	330pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A471K0K1H03B	X8L	100	470pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A681K0K1H03B	X8L	100	680pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A102K0K1H03B	X8L	100	1000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A152K0K1H03B	X8L	100	1500pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A222K0K1H03B	X8L	100	2200pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A332K0K1H03B	X8L	100	3300pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A472K0K1H03B	X8L	100	4700pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A682K0K1H03B	X8L	100	6800pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A103K0K1H03B	X8L	100	10000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A153K0K1H03B	X8L	100	15000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A223K0K1H03B	X8L	100	22000pF	±10%	3.6	3.5	6.0	5.0	2.5	0K1	500
	RHEL82A333K1K1H03B	X8L	100	33000pF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL82A473K1K1H03B	X8L	100	47000pF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL82A683K1K1H03B	X8L	100	68000pF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL82A104K1K1H03B	X8L	100	0.1µF	±10%	4.0	3.5	5.0	5.0	2.5	1K1	500
	RHEL82A154K2K1H03B	X8L	100	0.15µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500
	RHEL82A224K2K1H03B	X8L	100	0.22µF	±10%	5.5	4.0	6.0	5.0	3.15	2K1	500

Straight Taping (Lead Style:DB)

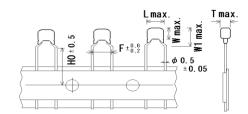


												Unit : mm	
Customer	Murata Part Number	T.C.	DC Rated	Cap.	Cap.		D	imensi	on (mr	n)		Dimension (LxW)	Pa qt
Part Number	marata r anvivamber		Volt. (V)	oup.	Tol.	L	W	W1	F	Т	H/H0	Lead Style	
	RHEL81E104K0DBH03A	X8L	25	0.1µF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	20
	RHEL81E154K0DBH03A	X8L	25	0.15µF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81E224K0DBH03A	X8L	25	0.22µF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81E334K1DBH03A	X8L	25	0.33µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81E474K1DBH03A	X8L	25	0.47µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81E684K1DBH03A	X8L	25	0.68µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81E105K1DBH03A	X8L	25	1.0µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81E155K2DBH03A	X8L	25	1.5µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2
	RHEL81E225K2DBH03A	X8L	25	2.2µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2
	RHEL81E335K2DBH03A	X8L	25	3.3µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2
	RHEL81E475K2DBH03A	X8L	25	4.7µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2
	RHEL81E106K3DBH03A	X8L	25	10µF	±10%	5.5	5.0	-	2.5	4.0	16.0	3DB	1
	RHEL81H221K0DBH03A	X8L	50	220pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H331K0DBH03A	X8L	50	330pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H471K0DBH03A	X8L	50	470pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H681K0DBH03A	X8L	50	680pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H102K0DBH03A	X8L	50	1000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H152K0DBH03A	X8L	50	1500pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H222K0DBH03A	X8L	50	2200pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H332K0DBH03A	X8L	50	3300pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H472K0DBH03A	X8L	50	4700pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H682K0DBH03A	X8L	50	6800pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H103K0DBH03A	X8L	50	10000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H153K0DBH03A	X8L	50	15000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H223K0DBH03A	X8L	50	22000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H333K0DBH03A	X8L	50	33000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H473K0DBH03A	X8L	50	47000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H683K0DBH03A	X8L	50	68000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H104K0DBH03A	X8L	50	0.1µF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2
	RHEL81H154K1DBH03A	X8L	50	0.15µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81H224K1DBH03A	X8L	50	0.22µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81H334K1DBH03A	X8L	50	0.33µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2
	RHEL81H474K2DBH03A	X8L	50	0.47µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2
	RHEL81H684K2DBH03A	X8L	50	0.68µF	±10%	5.5	4.0	-		3.15			2
	RHEL81H105K2DBH03A	X8L	50	1.0µF	±10%	5.5	4.0	-	2.5		16.0	2DB	2
	RHEL81H155K2DBH03A	X8L	50	1.5µF	±10%	5.5	4.0	_	2.5			2DB	2
	RHEL81H225K2DBH03A	X8L	50	2.2µF	±10%	5.5	4.0	_	2.5		16.0	2DB	2
	RHEL81H335K3DBH03A	X8L	50	3.3µF	±10%	5.5	5.0	_	2.5		16.0	3DB	1
	RHEL81H475K3DBH03A	X8L	50	3.5μr 4.7μF	±10%	5.5	5.0		2.5		16.0	3DB	1:
	RHEL82A221K0DBH03A	X8L	100	220pF	±10%	3.6	3.5		2.5	2.5	16.0	0DB	20

Straight Taping (Lead Style:DB)

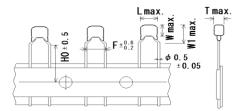


Inside Crimp Taping (Lead Style: M*)



									Onit . min				
Customer	Murata Part Number	T.C.	DC Rated Volt. (V)	Cap.	Dimension (mm)						Dimension (LxW)	Pack qty.	
Part Number	Ividiata i art Number	1.0.		Oap.	Tol.	L	W	W1	F	Т	H/H0	. ` ′ .	
	RHEL82A331K0DBH03A	X8L	100	330pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A471K0DBH03A	X8L	100	470pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A681K0DBH03A	X8L	100	680pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A102K0DBH03A	X8L	100	1000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A152K0DBH03A	X8L	100	1500pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A222K0DBH03A	X8L	100	2200pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A332K0DBH03A	X8L	100	3300pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A472K0DBH03A	X8L	100	4700pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A682K0DBH03A	X8L	100	6800pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A103K0DBH03A	X8L	100	10000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A153K0DBH03A	X8L	100	15000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A223K0DBH03A	X8L	100	22000pF	±10%	3.6	3.5	-	2.5	2.5	16.0	0DB	2000
	RHEL82A333K1DBH03A	X8L	100	33000pF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2000
	RHEL82A473K1DBH03A	X8L	100	47000pF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2000
	RHEL82A683K1DBH03A	X8L	100	68000pF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2000
	RHEL82A104K1DBH03A	X8L	100	0.1µF	±10%	4.0	3.5	-	2.5	2.5	16.0	1DB	2000
	RHEL82A154K2DBH03A	X8L	100	0.15µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2000
	RHEL82A224K2DBH03A	X8L	100	0.22µF	±10%	5.5	4.0	-	2.5	3.15	16.0	2DB	2000
	RHEL81E104K0M1H03A	X8L	25	0.1µF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81E154K0M1H03A	X8L	25	0.15µF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81E224K0M1H03A	X8L	25	0.22µF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81E334K1M1H03A	X8L	25	0.33µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81E474K1M1H03A	X8L	25	0.47µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81E684K1M1H03A	X8L	25	0.68µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81E105K1M1H03A	X8L	25	1.0µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81E155K2M1H03A	X8L	25	1.5µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81E225K2M1H03A	X8L	25	2.2µF	±10%	5.5	4.0	6.0	5.0	3.15		2M1	2000
	RHEL81E335K2M1H03A	X8L	25	3.3µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81E475K2M1H03A	X8L	25	4.7µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81E106K3M1H03A	X8L	25	10µF	±10%	5.5	5.0	7.5	5.0	4.0	16.0	3M1	1500
	RHEL81E226MWM1H03A	X8L	25	22µF	±20%	5.5	7.5	10.0	5.0	4.0	16.0	WM1	1500
	RHEL81H221K0M1H03A	X8L	50	220pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H331K0M1H03A	X8L	50	330pF	±10%	3.6	3.5	6.0	5.0	2.5		0M1	2000
	RHEL81H471K0M1H03A	X8L	50	470pF	±10%	3.6	3.5				16.0		2000
	RHEL81H681K0M1H03A	X8L	50	680pF	±10%	3.6	3.5	6.0	5.0				2000
	RHEL81H102K0M1H03A	X8L	50	1000pF	±10%	3.6	3.5	6.0	5.0				2000
	RHEL81H152K0M1H03A	X8L	50	1500pF	±10%	3.6	3.5	6.0	5.0				2000
	RHEL81H222K0M1H03A	X8L	50	2200pF	±10%	3.6	3.5		5.0				2000
	RHEL81H332K0M1H03A	X8L	50	3300pF	±10%	3.6	3.5	6.0	5.0				2000
	RHEL81H472K0M1H03A	X8L	50	4700pF	±10%	3.6	3.5	6.0	5.0				2000
	TATILLO IT IT ZIXOWITI IOSA	AUL	50	47 00pi	±1070	5.0	5.5	0.0	5.0	2.0	10.0	OIVII	2000

Inside Crimp Taping (Lead Style: M*)



Customer Part Number	Murata Part Number	T.C.	DC Rated Volt.	Сар.	Cap. Tol.	Dimension (mm)					I	Dimension (LxW)	qty.
T dit Tumbor			(V)		101.	L	W	W1	F	Т	H/H0	Lead Style	(pcs)
	RHEL81H682K0M1H03A	X8L	50	6800pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H103K0M1H03A	X8L	50	10000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H153K0M1H03A	X8L	50	15000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H223K0M1H03A	X8L	50	22000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H333K0M1H03A	X8L	50	33000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H473K0M1H03A	X8L	50	47000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H683K0M1H03A	X8L	50	68000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H104K0M1H03A	X8L	50	0.1µF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL81H154K1M1H03A	X8L	50	0.15µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81H224K1M1H03A	X8L	50	0.22µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81H334K1M1H03A	X8L	50	0.33µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL81H474K2M1H03A	X8L	50	0.47µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81H684K2M1H03A	X8L	50	0.68µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81H105K2M1H03A	X8L	50	1.0µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81H155K2M1H03A	X8L	50	1.5µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81H225K2M1H03A	X8L	50	2.2µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL81H335K3M1H03A	X8L	50	3.3µF	±10%	5.5	5.0	7.5	5.0	4.0	16.0	3M1	1500
	RHEL81H475K3M1H03A	X8L	50	4.7µF	±10%	5.5	5.0	7.5	5.0	4.0	16.0	3M1	1500
	RHEL81H106MWM1H03A	X8L	50	10µF	±20%	5.5	7.5	10.0	5.0	4.0	16.0	WM1	1500
	RHEL82A221K0M1H03A	X8L	100	220pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A331K0M1H03A	X8L	100	330pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A471K0M1H03A	X8L	100	470pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A681K0M1H03A	X8L	100	680pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A102K0M1H03A	X8L	100	1000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A152K0M1H03A	X8L	100	1500pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A222K0M1H03A	X8L	100	2200pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A332K0M1H03A	X8L	100	3300pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A472K0M1H03A	X8L	100	4700pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A682K0M1H03A	X8L	100	6800pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A103K0M1H03A	X8L	100	10000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A153K0M1H03A	X8L	100	15000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A223K0M1H03A	X8L	100	22000pF	±10%	3.6	3.5	6.0	5.0	2.5	16.0	0M1	2000
	RHEL82A333K1M1H03A	X8L	100	33000pF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL82A473K1M1H03A	X8L	100	47000pF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL82A683K1M1H03A	X8L	100	68000pF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL82A104K1M1H03A	X8L	100	0.1µF	±10%	4.0	3.5	5.0	5.0	2.5	16.0	1M1	2000
	RHEL82A154K2M1H03A	X8L	100	0.15µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000
	RHEL82A224K2M1H03A	X8L	100	0.22µF	±10%	5.5	4.0	6.0	5.0	3.15	16.0	2M1	2000

Reference only

Spe	cification									
No.	Tes	t Item	Specification	Test Method (Compliant Standard:AEC-Q200)						
1	Pre-and Post-S	Stress								
2	High	Appearance	No defects or abnormalities.	Sit the capacitor for 1000±12 hours at 150±3°C. Let sit for 24±2 hours						
	Temperature	Capacitance	within ±12.5%	at *room condition, then measure.						
	Exposure	Change								
	(Storage)	D.F.	0.04 max.	•Pretreatment						
	(Otorago)	I.R.	More than 1,000MΩ or 50MΩ•μF	Perform the heat treatment at 150+0/-10°C for 60±5 min and						
		i.ix.	(Whichever is smaller)	then let sit for 24±2 hours at *room condition.						
2	Temperature	Annogrange	No defects or abnormalities except color	Perform the 1000 cycles according to the four heat treatments listed						
3		Appearance	'							
	Cycling	9 ;	change of outer coating.	in the following table. Let sit for 24±2 hours at *room condition, then measi						
		Capacitance	within ±12.5%	Step 1 2 3 4						
		Change		Temp55+0/-3 Room 150+3/-0 Room						
		D.F.	0.05 max.	(°C) Temp. Temp.						
		I.R.	1,000MΩ or 50MΩ•μF min.	Time 15±3 1 15±3 1						
			(Whichever is smaller)	(min.)						
				•Pretreatment						
				Perform the heat treatment at 150+0/-10°C for 60±5 min and						
				then let sit for 24±2 hours at *room condition.						
4	Moisture	Appearance	No defects or abnormalities.	Apply the 24 hours heat (25 to 65°C) and humidity (80 to 98%)						
	Resistance	Capacitance	within ±12.5%	treatment shown below, 10 consecutive times.						
		Change		Let sit for 24±2 hours at *room condition, then measure.						
		D.F.	0.05 max.							
		I.R.	500MΩ or 25MΩ•μF min.	Humidity 80~98% Humidity 80~98% Humidity						
		i.i.c.	(Whichever is smaller)	70 90~98% V 90~98% V 90~98%						
			(Willichever is smaller)	65						
				60						
				55						
				§50 §45						
				840						
				[535						
				730 V V V V V V V V V V V V V V V V V V V						
				25 20 +10						
				15 - 2 °C						
				10 Initial measurement						
				5						
				0						
				-5						
				One cycle 24 hours 0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24						
				Hours						
				Pretreatment						
				Perform the heat treatment at 150+0/-10°C for 60±5 min and						
				then let sit for 24±2 hours at *room condition.						
5	Biased	Appearance	No defects or abnormalities.	Apply the rated voltage and DC1.3+0.2/-0V (add $100k\Omega$ resistor)						
	Humidity	Capacitance	within ±12.5%	at 85±3°C and 80 to 85% humidity for 1,000±12 hours.						
		Change		Remove and let sit for 24±2 hours at *room condition, then measure.						
		D.F.	0.05 max.	The charge/discharge current is less than 50mA.						
		I.R.	500MΩ or 25MΩ•μF min.	• Pretreatment						
			(Whichever is smaller)	Perform a heat treatment at 150+0/-10°C for one hour.						
			, and a simulation,	and then set at room temperature for 24±2 hours.						
6	Operational	Appearation	No defects or abnormalities assert as to	·						
6	Operational	Appearance	No defects or abnormalities except color	Apply 150% of the rated voltage for 1,000±12 hours at 150±3°C.						
	Life		change of outer coating.	Let sit for 24±2 hours at *room condition, then measure.						
		Capacitance	within ±12.5%	The charge/discharge current is less than 50mA.						
		Change	1	•Pretreatment						
		D.F.	0.04 max.	Apply test voltage for 60±5 min at test temperature.						
		I.R.	1,000M Ω or 50M Ω •μF min.	Remove and let sit for 24±2 hours at *room condition.						
		<u> </u>	(Whichever is smaller)							
7	External Visua	I	No defects or abnormalities.	Visual inspection.						
В	Physical Dime	nsion	Within the specified dimensions.	Using calipers and micrometers.						
9	Marking		To be easily legible.	Visual inspection.						
0	Resistance	Appearance	No defects or abnormalities.	Per MIL-STD-202 Method 215						
J		- ' '								
	to Solvents	Capacitance	Within the specified tolerance.	Solvent 1 : 1 part (by volume) of isopropyl alcohol						
		D.F.	0.025 max.	3 parts (by volume) of mineral spirits						
		I.R.	More than 10,000MΩ or 500 MΩ∙μF	Solvent 2 : Terpene defluxer						
			(Whichever is smaller)	Solvent 3: 42 parts (by volume) of water						
				•						
				1part (by volume) of propylene glycol monomethyl ether						
				1part (by volume) of propylene glycol monomethyl ether 1 part (by volume) of monoethanolamine						

Reference only

No.	Tes	t Item	Specification	Т	Test Method	(Compliant St	andard:AEC-	Q200)		
11	Mechanical	Appearance	No defects or abnormalities.	Test Method (Compliant Standard:AEC-Q200) Three shocks in each direction should be applied along 3						
	Shock	Capacitance	Within the specified tolerance.	mutually perpend			-			
		D.F.	0.025 max.	The specified tes		· ·				
				duration: 0.5ms,	, peak value	: 1500G and	velocity chang	ge: 4.7m/s.		
12	Vibration	Appearance	No defects or abnormalities.	The capacitor sh						
		Capacitance	Within the specified tolerance.	having a total am	•		•			
		D.F.	0.025 max.	uniformly between	•					
				The frequency ra						
				should be travers	-					
				should be applied		•				
				directions (total of		0 000 0	araan, porpor	raioaiai		
13-1	Resistance	Appearance	No defects or abnormalities.	The lead wires s		nersed in the	melted solder	1.5 to 2.0mm		
	to Soldering	Capacitance	Within ±7.5%	from the root of t				1.0 to 2.011111		
	Heat	Change	VVIIII 1 1 .0 /0	nom the root of t	omma at 20	0010 0 101 10	±1 300011d3.			
	(Non-	Dielectric	No defects.	Pre-treatment						
	Preheat)	Strength	ino delects.		l ho stored s	+ 150±0/ 10°0	for one hou			
	rielleat)	Ŭ		Capacitor should						
		(Between		then place at *ro		101 24±2 110u	irs before mili	ai measurement.		
		terminals)		Post-treatment		04.0 h		-1141		
12.0	Desisten	Ann c = ==	No defects or objective.	Capacitor should						
-	Resistance	Appearance	No defects or abnormalities.	First the capacito						
	to Soldering	Capacitance	Within ±7.5%	Then, the lead w						
	Heat	Change		1.5 to 2.0mm fro	m the root of	terminal at 2	60±5°C for 7.	5+0/-1 seconds.		
	(On-	Dielectric	No defects.							
	Preheat)	Strength		Pre-treatment						
		(Between		Capacitor should	be stored a	nt 150+0/-10°0	C for one hou	Γ,		
		terminals)		then place at *ro	om condition	for 24±2 hou	irs before initia	al measurement.		
				 Post-treatment Capacitor should be stored for 24±2 hours at *room condition. 						
				Capacitor should	be stored fo	or 24±2 hours	at *room cor	dition.		
13-3	Resistance	Appearance	No defects or abnormalities.	Test condition						
	to Soldering	Capacitance	Within ±7.5%	Temperature of	firon-tip: 350	0±10°C				
	Heat	Change		Soldering time: 3.5±0.5 seconds						
	(soldering	Dielectric	No defects	Soldering positio	n					
	iron method)	Strength		Straight Lead :	1.5 to 2.0mm	n from the roo	t of terminal.			
		(Between		Crimp Lead : 1.	.5 to 2.0mm f	rom the end	of lead bend.			
		terminals)								
				 Pre-treatment 						
				Capacitor should	be stored a	at 150+0/-10°0	C for one hou	r,		
				then place at *ro	om condition	for 24±2 hou	rs before initia	al measurement.		
				 Post-treatment 						
				Capacitor should	be stored fo	or 24±2 hours	at *room cor	ndition.		
14	Thermal	Appearance	No defects or abnormalities.	Perform the 300	cycles accor	ding to the tw	o heat treatm	ents listed in the		
	Shock	Capacitance	within ±12.5%	following table (N	Maximum trai	nsfer time is 2	20 seconds.).			
		Change		Let sit for 24±2 h	ours at *roor	n condition, th	nen measure.			
		D.F.	0.05 max.] [Step	1	2			
-		I.R.	1,000MΩ or 50MΩ • μF min.	7	Temp.	EF : 0/ 0	150.0/0			
		Ī	(Whichever is smaller)		(°C)	-55+0/-3	150+3/-0			
							İ	1		
					Time	45.0	45.0			
					Time (min.)	15±3	15±3			
				•Pretreatment		15±3	15±3			
				•Pretreatment Perform the heat	(min.)			and		
				Perform the heat	(min.) t treatment a	t 150+0/-10°C	for 60±5 min	and		
15	ESD	Appearance	No defects or abnormalities.		(min.) t treatment a ±2 hours at *	t 150+0/-10°C	for 60±5 min	and		
15	ESD	Appearance Capacitance		Perform the heat then let sit for 24	(min.) t treatment a ±2 hours at *	t 150+0/-10°C	for 60±5 min	and		
15	ESD	Capacitance	Within the specified tolerance.	Perform the heat then let sit for 24	(min.) t treatment a ±2 hours at *	t 150+0/-10°C	for 60±5 min	and		
15	ESD	Capacitance D.F.	Within the specified tolerance. 0.025 max.	Perform the heat then let sit for 24	(min.) t treatment a ±2 hours at *	t 150+0/-10°C	for 60±5 min	and		
15	ESD	Capacitance	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ • μF	Perform the heat then let sit for 24	(min.) t treatment a ±2 hours at *	t 150+0/-10°C	for 60±5 min	and		
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ • μF (Whichever is smaller)	Perform the heat then let sit for 24 Per AEC-Q200-0	(min.) t treatment a ±2 hours at *	t 150+0/-10°C room condition	c for 60±5 min			
	ESD Solderability	Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with	Perform the heat then let sit for 24 Per AEC-Q200-0	(min.) t treatment a ±2 hours at * 202	t 150+0/-10°C room condition	c for 60±5 min			
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with uniform coating on the axial direction	Perform the heat then let sit for 24 Per AEC-Q200-0 The terminal of cethanol (25% ros	(min.) t treatment a ±2 hours at ' 002 capacitor is d	t 150+0/-10°C (room condition ipped into a s propotion).	c for 60±5 min			
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with	Perform the heat then let sit for 24 Per AEC-Q200-0 The terminal of cethanol (25% ross Immerse in solder	t treatment a ±2 hours at * 202 capacitor is d sin in weight er solution fo	t 150+0/-10°C (room condition ipped into a s propotion). r 2±0.5 secon	c for 60±5 min	n		
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with uniform coating on the axial direction	Perform the heat then let sit for 24 Per AEC-Q200-0 The terminal of cethanol (25% ros Immerse in solde In both cases the	t treatment a ±2 hours at * 202 capacitor is d sin in weight er solution fo e depth of dip	t 150+0/-10°C (room condition ipped into a s propotion). r 2±0.5 secon	c for 60±5 min	n		
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with uniform coating on the axial direction	Perform the heat then let sit for 24 Per AEC-Q200-0 The terminal of cethanol (25% ros Immerse in solde In both cases the the terminal body	(min.) It treatment as the treatment as	ipped into a s propotion). r 2±0.5 secon	on. clotion of rosi ds about 1.5 to 2	n		
		Capacitance D.F.	Within the specified tolerance. 0.025 max. More than 10,000MΩ or 500MΩ·μF (Whichever is smaller) Lead wire should be soldered with uniform coating on the axial direction	Perform the heat then let sit for 24 Per AEC-Q200-0 The terminal of cethanol (25% ros Immerse in solde In both cases the	(min.) It treatment as the treatment as	ipped into a s propotion). r 2±0.5 secon	on. clotion of rosi ds about 1.5 to 2	n		

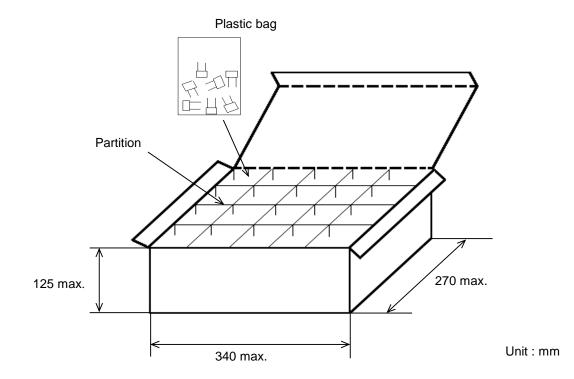
Reference only

lo.	Tes	st Item		Specification	Test Method (Compliant Standard:AEC-Q200)					
17	Electrical	Appearance	No defects or	abnormalities.	Visual inspection. The capacitance/D.F. should be measured at 25°C at the					
	Characte-	Capacitance	Within the spe	cified tolerance.						
	rization	D.F.	0.025 max.		frequency and voltage shown in the table.					
					Nominal Cap. Frequency Voltage					
					C≦10μF 1±0.1kHz AC1±0.2V (r.m.s.)					
					C>10μF 120±24Hz AC0.5±0.1V (r.m.s.)					
		Insulation	Room	10,000MΩ or 500MΩ•μF min.	The insulation resistance should be measured at 25±3 °C with					
		Resistance	Temperature	(Whichever is smaller)	a DC voltage not exceeding the rated voltage at normal temperatu					
		(I.R.)	Tomporature	(vvinenever ie einanei)	and humidity and within 2 min. of charging.					
		()			(Charge/Discharge current ≤ 50mA.)					
			High	100MΩ or 5MΩ•μF min.	The insulation resistance should be measured at 150±3 °C with					
			Temperature	(Whichever is smaller)	a DC voltage not exceeding the rated voltage at normal temperatu					
			remperature	(Willeflever is smaller)	and humidity and within 2 min. of charging.					
		Dielectric	Between	No defects or abnormalities.	(Charge/Discharge current ≤ 50mA.)					
			Terminals	no defects of abriormanties.	The capacitor should not be damaged when DC voltage of 250%					
		Strength	reminais		of the rated voltage is applied between the terminations for					
					1 to 5 seconds.					
			Terminal To		(Charge/Discharge current ≤ 50mA.)					
			External	No defects or abnormalities.	The capacitor is placed in a container with metal					
			Resin		balls of 1mm diameter so that each terminal,					
					short-circuit is kept approximately 2mm from Approx the helle and 350% of the reted DC voltage is					
					the balls, and 250% of the fated DC voltage is					
					impressed for 1 to 5 seconds between					
					capacitor terminals and metal balls.					
		<u> </u>	<u> </u>	1	(Charge/Discharge current ≤ 50mA.) ba					
18	Terminal Tensile		Termination not to be broken or loosened.		As in the figure, fix the capacitor body, apply the force gradually					
	Strength	Strength			to each lead in the radial direction of the capacitor until reaching					
					10N and then keep the force applied for 10±1 seconds.					
					<u>'////</u>					
					F] 					
		Dandin -	Ti							
		Bending	remination no	ot to be broken or loosened.	Each lead wire should be subjected to a force of 2.5N and then					
		Strength			be bent 90° at the point of egress in one direction.					
					Each wire is then returned to the original position and bent 90°					
	.		10-0		in the opposite direction at the rate of one bend per 2 to 3 seconds					
19	Capacitance		-55 to 125°C :		The capacitance change should be measured after 5min.					
	Temperature	•		within +15/-40%	at each specified temperature step.					
	Characteristic	S			Step Temperature(°C)					
					1 25±2					
					2 -55±3					
					3 25±2					
			1		4 150±3					
					5 25±2					
					The ranges of capacitance change compared with the above					
					25°C value over the temperature ranges shown in the table					
					should be within the specified ranges.					
			1		•Pretreatment					
			1		Perform the heat treatment at 150+0/-10°C for 60±5 min and					
					Choin the fleat treatment at 15010/10 0 for 00±5 min and					
					then let sit for 24±2 hours at *room condition.					

6. Packing specification

•Bulk type (Packing style code : B)

The size of packing case and packing way



The number of packing = *1 Packing quantity \times *2 n

*1 : Please refer to [Part number list].

*2 : Standard n = 20 (bag)

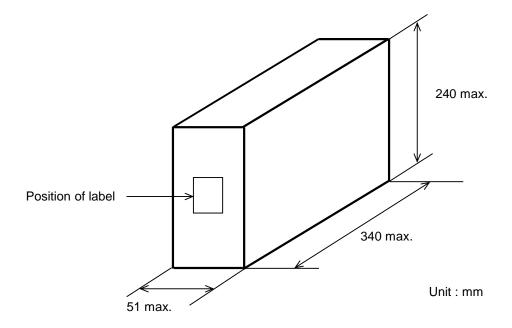
Note)

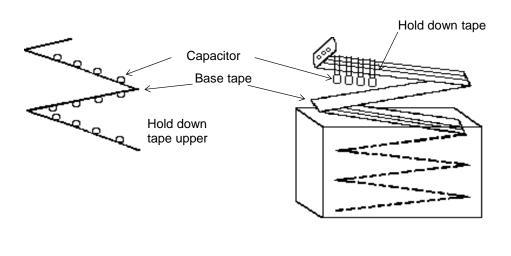
The outer package and the number of outer packing be changed by the order getting amount.

•Ammo pack taping type (Packing style code : A)

A crease is made every 25 pitches, and the tape with capacitors is packed zigzag into a case. When body of the capacitor is piled on other body under it.

The size of packing case and packing way



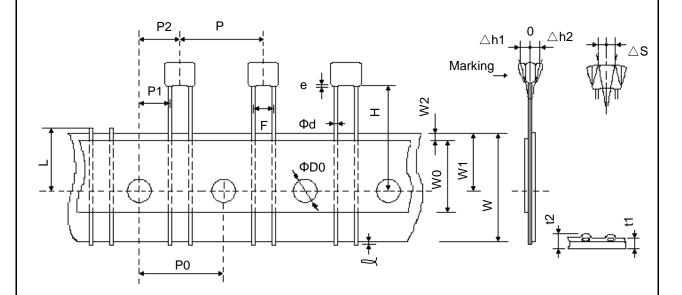


7. Taping specification

7-1. Dimension of capacitors on tape

Straight taping type < Lead Style : DB >

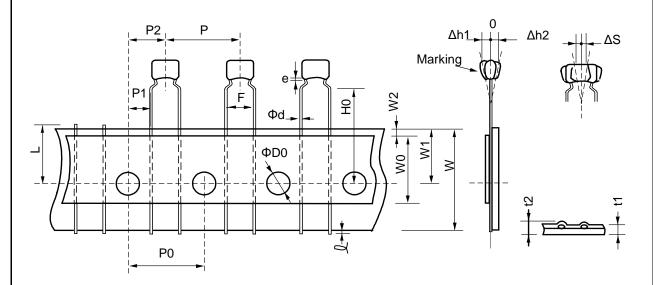
Pitch of component 12.7mm / Lead spacing 2.5mm



Unit: mm

Item	Code	Dimensions	Remarks
Pitch of component	Р	12.7+/-1.0	
Pitch of sprocket hole	P0	12.7+/-0.2	
Lead spacing	F	2.5+0.4/-0.2	
Length from hole center to component center		6.35+/-1.3	Deviation of progress direction
Length from hole center to lead	P1	5.1+/-0.7	
Deviation along tape, left or right defect	ΔS	0+/-2.0	They include deviation by lead bend
Carrier tape width	W	18.0+/-0.5	
Position of sprocket hole	W1	9.0+0/-0.5	Deviation of tape width direction
Lead distance between reference and bottom plane	Н	16.0+/-0.5	
Protrusion length	l	0.5 max.	
Diameter of sprocket hole	ФD0	4.0+/-0.1	
Lead diameter	Фd	0.5+/-0.05	
Total tape thickness	t1	0.6+/-0.3	They include hold down tape
Total thickness of tape and lead wire	t2	1.5 max.	thickness
Daviation agrees tape	∆h1	1.0 max.	
Deviation across tape	∆ h2	1.0 Illax.	
Portion to cut in case of defect	L	11.0+0/-1.0	
Hold down tape width	W0	9.5 min.	
Hold down tape position	W2	1.5+/-1.5	
Coating extension on lead	е	1.5 max.	

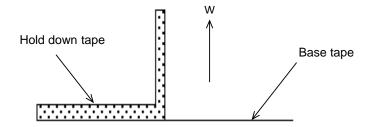
Inside crimp taping type < Lead Style : M1 > Pitch of component 12.7mm / Lead spacing 5.0mm



Item	Code	Dimensions	Remarks
Pitch of component	Р	12.7+/-1.0	
Pitch of sprocket hole	P0	12.7+/-0.2	
Lead spacing	F	5.0+0.6/-0.2	
Length from hole center to component center		6.35+/-1.3	Deviation of progress direction
Length from hole center to lead	P1	3.85+/-0.7	
Deviation along tape, left or right defect	ΔS	0+/-2.0	They include deviation by lead bend
Carrier tape width	W	18.0+/-0.5	
Position of sprocket hole	W1	9.0+0/-0.5	Deviation of tape width direction
Lead distance between reference and bottom plane	H0	16.0+/-0.5	
Protrusion length	l	0.5 max.	
Diameter of sprocket hole	ФD0	4.0+/-0.1	
Lead diameter	Фd	0.5+/-0.05	
Total tape thickness	t1	0.6+/-0.3	They include hold down tape
Total thickness of tape and lead wire	t2	1.5 max.	thickness
Doviation across tapo	∆h1	2.0 max. (Di	mension code : W)
Deviation across tape	Δh2	1.0 max. (ex	ccept as above)
Portion to cut in case of defect	L	11.0+0/-1.0	
Hold down tape width	W0	9.5 min.	
Hold down tape position	W2	1.5+/-1.5	
Coating extension on lead	е	Up to the end of	crimp

7-2. Splicing way of tape

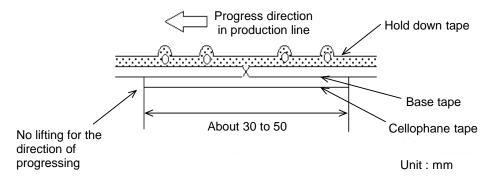
1) Adhesive force of tape is over 3N at test condition as below.



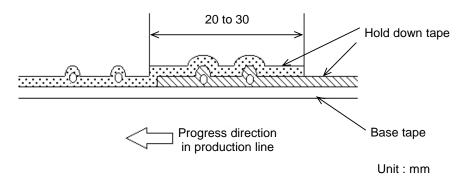
2) Splicing of tape

- (a) When base tape is spliced
 - •Base tape shall be spliced by cellophane tape.

(Total tape thickness shall be less than 1.05mm.)



- (b) When hold down tape is spliced
- •Hold down tape shall be spliced with overlapping. (Total tape thickness shall be less than 1.05mm.)



- (c) When both tape are spliced
 - •Base tape and hold down tape shall be spliced with splicing tape.
- 3) Missing components
 - •There should be no consecutive missing of more than three components.
 - •The number of missing components should be not more than 0.5 % of total components that should be present in a Ammo pack.